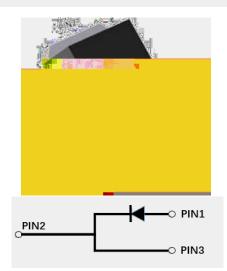
V <sub>RRM</sub>	650V		
I <sub>F</sub> (135°C)	22A		
Q <sub>C</sub>	62nC		



Positive temperature coefficient Temperature-independent switching Maximum working temperature at 175 °C Unipolar devices and zero reverse recovery current Zero forward recovery current Essentially no switching losses Reduction of heat sink requirements High-frequency operation Reduction of EMI

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

: TO-263 Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free : Tin plated leads : As marked

Device marking code			D106520BQG2			
Reverse voltage (repetitive peak) @ T <sub>j</sub> =25°C	V <sub>RRM</sub>	V	650			
Reverse voltage (Surge Peak) @ T <sub>j</sub> =25°C	V <sub>RSM</sub>	V	650			
Reverse voltage (DC) @ T <sub>j</sub> =25°C	V <sub>DC</sub>	V	650			
Continuous forward current @ T <sub>c</sub> =25°C			48			
Continuous forward current @ T <sub>c</sub> =135°C	IF	А	22			
Continuous forward current @ T <sub>c</sub> =140°C			20			
Non-repetitive peak forward surge current @ $T_c=25$ °C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	160			
Power Dissipation @ T <sub>c</sub> =25°C	Ρτοτ	w	144			
Power Dissipation@ T <sub>c</sub> =110°C	Гтот		62			
i²t Value@ Tc=25°C ,tp=10ms	i <sup>2</sup> dt	A <sup>2</sup> S	128			
Operating junction and Storage temperature range	$T_{j}$ , $T_{stg}$	°C	-55 to +175			

## (T<sub>C</sub>=25<sup>°</sup>C Unless otherwise specified)

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Forward voltage drop	V <sub>F</sub>	v	I <sub>F</sub> =20A, T <sub>j</sub> =25°C	1.35	1.55
			I <sub>F</sub> =20A, T <sub>j</sub> =175°C	1.75	-
Reverse leakage current	I <sub>R</sub>	μΑ	V <sub>R</sub> =650V, T <sub>j</sub> =25°C	1	25
			V <sub>R</sub> =650V, T <sub>j</sub> =175°C	5	-
Total capacitive charge	Q <sub>c</sub>	nC	$V_R$ =400V, T <sub>j</sub> =25°C , QC= $_0^{VR}$ C(V)dV	62	-
Total capacitance	С	pF	V <sub>R</sub> =0V, f=1MHZ	1157	-
			V <sub>R</sub> =200V, f=1MHZ	115.6	-
			V <sub>R</sub> =400V, f=1MHZ	107	-
Capacitance Stored Energy	Ec	μJ	V <sub>R</sub> =400V	7.8	-

## (Ta=25 $^{\circ}$ C Unless otherwise specified)

Thermal resistance	R <sub>J-C</sub>	°C <i>W</i>	1.04

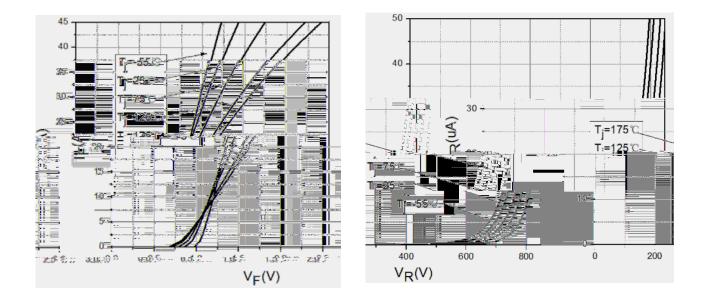


Figure 1. Forward Characteristics

Figure2. Reverse Characteristic

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